FAIRCHILD

SEMICONDUCTOR

74LCXR2245 Low Voltage Bidirectional Transceiver with 5V Tolerant Inputs and Outputs and 26Ω Series Resistors on Both A and B Ports

General Description

The LCXR2245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus oriented applications. The device is designed for low voltage (2.5V and 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment. The T/R input determines the direction of data flow through the device. The $\overline{\text{OE}}$ input disables both the A and B ports by placing them in a high impedance state. The 26Ω series resistor helps reduce output overshoot and undershoot.

The LCXR2245 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

- Features
- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- \blacksquare 8.0 ns t_{PD} max (V_{CC} = 3.3V), 10 μA I_{CC} max
- Power down high impedance inputs and outputs

October 2000

Revised October 2000

- Supports live insertion/withdrawal (Note 1)
- ±12 mA output drive ($V_{CC} = 3.0V$)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- Equivalent 26Ω series resistor on all outputs
 ESD performance:
- Human body model > 2000V Machine model > 200V

Note 1: To ensure the high-impedance state during power up or down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

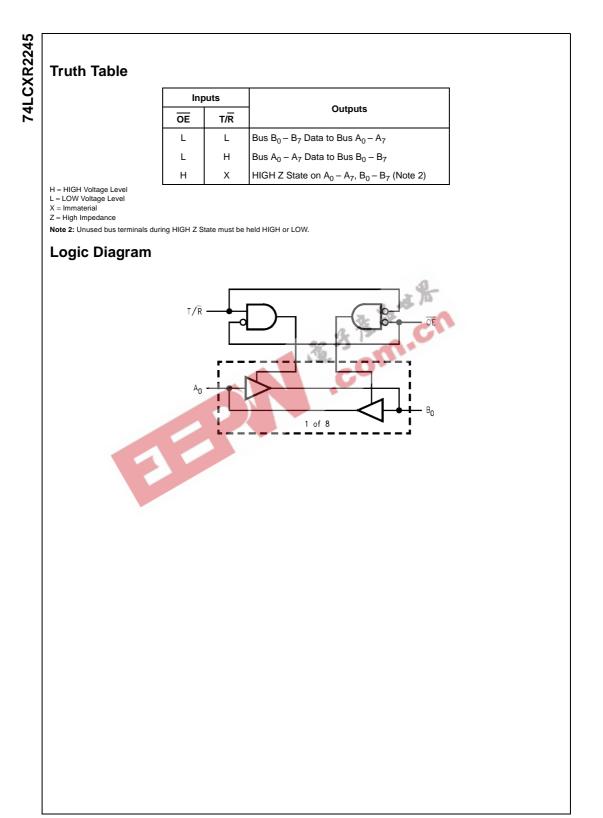
Ordering Code:

Order Number	Package Number	Package Description
74LCXR2245WM	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74LCXR2245SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LCXR2245MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), EIAJ TYPE II, 5.3mm Wide
74LCXR2245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Devices also available	in Tape and Reel. Specify	by appending the suffix letter "X" to the ordering code.

Logic Symbol **Connection Diagram** T/R 20 OF A₀ 19 Bo A₁ Α, Α, B₂ Β₃ **Pin Descriptions** Α5 Bz Pin Names Description A₆ 13 Be OE Output Enable Input Α-12 B₆ GND 10 11 T/R Transmit/Receive Input A₀-A₇ Side A Inputs or 3-STATE Outputs B₀-B₇ Side B Inputs or 3-STATE Outputs

www.fairchildsemi.com

Resistors on Both A and B Ports



Absolute Maximum Ratings(Note 3)

Symbol	Parameter	Value	Conditions	Units	
V _{CC}	Supply Voltage	-0.5 to +7.0		V	
VI	DC Input Voltage	-0.5 to +7.0		V	
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE	V	
		–0.5 to $V_{CC}{+}0.5$	Output in HIGH or LOW State (Note 4)	v	
I _{IK}	DC Input Diode Current	-50	V _I < GND	mA	
I _{ОК}	DC Output Diode Current	-50	V _O < GND		
		+50	V _O > V _{CC}	mA	
I _O	DC Output Source/Sink Current	±50		mA	
I _{CC}	DC Supply Current per Supply Pin	±100		mA	
I _{GND}	DC Ground Current per Ground Pin	±100		mA	
T _{STG}	Storage Temperature	-65 to +150		°C	

Recommended Operating Conditions (Note 5)

Symbol	Parameter	Min	Max	Units	
V _{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	v
VI	Input Voltage	1 St. 34	0	5.5	V
Vo	Output Voltage	HIGH or LOW State	0	V _{CC}	V
		3-STATE	0	5.5	v
_{OH} /I _{OL}	Output Current	$V_{CC} = 3.0V - 3.6V$		±12	
		V _{CC} = 2.7V - 3.0V V _{CC} = 2.3V - 2.7V		±8	mA
		V _{CC} = 2.3V - 2.7V		±4	
Г _А	Free-Air Operating Temperature		-40	85	°C
Δt/ΔV	Input Edge Rate, $V_{IN} = 0.8V - 2.0V$, $V_{CC} = 3.0V$		0	10	ns/V

Note 3: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recom-mended Operating Conditions" table will define the conditions for actual device operation. Note 4: I₀ Absolute Maximum Rating must be observed. Note 5: Unused inputs or I/O pins must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	v _{cc}	$T_A = -40^{\circ}C$ to $+85^{\circ}C$		Units
Symbol		Conditions	(V)	Min	Max	_ Units
VIH	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		v
V _{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 - 3.6		0.8	v
V _{OH}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.3 - 3.6	V _{CC} – 0.2		
		$I_{OH} = -4 \text{ mA}$	2.3	1.8		
		$I_{OH} = -4 \text{ mA}$	2.7	2.2		v
		$I_{OH} = -6 \text{ mA}$	3.0	2.4		
		I _{OH} = -8 mA	2.7	2.0		
		I _{OH} = -12 mA	3.0	2.0		
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.3 - 3.6		0.2	
		$I_{OL} = 4 \text{ mA}$	2.3		0.6	
		$I_{OL} = 4 \text{ mA}$	2.7		0.4	v
		$I_{OL} = 6 \text{ mA}$	3.0		0.55	v
		$I_{OL} = 8 \text{ mA}$	2.7		0.6	
		I _{OL} = 12 mA	3.0		0.8	1
l _l	Input Leakage Current	$0 \le V_I \le 5.5V$	2.3 - 3.6		±5.0	μΑ
I _{OZ}	3-STATE I/O Leakage	$0 \le V_O \le 5.5V$ $V_I = V_{IH} \text{ or } V_{IL}$	2.3 - 3.6		±5.0	μA

74LCXR2245

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	v _{cc}	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units
		Conditions	(V)	Min	Max	Units
I _{OFF}	Power-Off Leakage Current	V_{I} or $V_{O} = 5.5V$	0		10	μA
I _{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 - 3.6		10	
		$3.6V \le V_I, V_O \le 5.5V$ (Note 6)	2.3 - 3.6		±10	μA
Δl _{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 - 3.6		500	μA

Note 6: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

		$T_A = -40^{\circ}C$ to $+85^{\circ}C$, $R_L = 500\Omega$						
Symbol	Parameter	$V_{CC} = 3.3V \pm 0.3V$ $C_L = 50 \text{ pF}$		V _{CC} = 2.7V C _L = 50 pF		$V_{CC} = 2.5V \pm 0.2V$ $C_L = 30 \text{ pF}$		Units
Symbol	Falailietei							
		Min	Max	Min	Max	Min	Max	
t _{PHL}	Propagation Delay	1.5	8.0	1.5	9.0	1.5	9.6	
t _{PLH}	A _n to B _n or B _n to A _n	1.5	8.0	1.5	9.0	1.5	9.6	ns
t _{PZL}	Output Enable Time	1.5	9.5	1.5	10.5	1.5	11.0	-
t _{PZH}		1.5	9.5	1.5	10.5	1.5	11.0	ns
t _{PLZ}	Output Disable Time	1.5	7.5	1.5 🍣	8.5	1.5	9.0	ns
t _{PHZ}		1.5	7.5	1.5	8.5	1.5	9.0	115
t _{OSHL}	Output to Output Skew		1.0	36. 3				ns
t _{OSLH}	(Note 7)		1.0					115

Note 7: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (toSHL) or LOW-to-HIGH (toSLH).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	Vcc	T _A = 25°C	Units
Cymbol	i urumeter	Contaitions	(V)	Typical	onno
V _{OLP}	Quiet Output Dynamic Peak VOL	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	0.5	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	0.4	v
V _{OLV}	Quiet Output Dynamic Valley VOL	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	0.5	V
		$C_L=30 \text{ pF}, V_{IH}=2.5 \text{V}, V_{IL}=0 \text{V}$	2.5	0.4	v

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{I/O}	Input/Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	V_{CC} = 3.3V, V_I = 0V or V_{CC} , f = 10 MHz	25	pF

